



## 2A SURFACE MOUNT GLASS PASSIVATED BRIDGE RECTIFIER

### FEATURES:

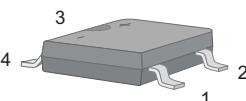
- Glass Passivated Chip Junction
- Reverse Voltage - 100 to 1000 V
- Forward Current - 2.0 A
- Fast reverse recovery time
- Designed for Surface Mount Application

### PINNING

PIN	DESCRIPTION
1	Input Pin ( ~ )
2	Input Pin ( ~ )
3	Output Anode ( + )
4	Output Cathode ( - )

### MECHANICAL DATA

- Case: ABS/LBF
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 88mg/0.0029oz



ABS/LBF Package

### Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	UTB1S-20	UTB2S-20	UTB4S-20	UTB6S-20	UTB8S-20	UTB10S-20	Units			
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	100	200	400	600	800	1000	V			
Maximum RMS voltage	V <sub>RMS</sub>	70	140	280	420	560	700	V			
Maximum DC Blocking Voltage	V <sub>DC</sub>	100	200	400	600	800	1000	V			
Average Rectified Output Current at T <sub>c</sub> = 125 °C	I <sub>o</sub>	2.0						A			
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I <sub>FSM</sub>	55						A			
Maximum Forward Voltage at 2 A	V <sub>F</sub>	1.0		1.4	1.65			V			
Maximum DC Reverse Current T <sub>a</sub> = 25 °C at Rated DC Blocking Voltage T <sub>a</sub> = 125 °C	I <sub>R</sub>	5.0 100						μA			
Typical Junction Capacitance <sup>1)</sup>	C <sub>j</sub>	35						pF			
Maximum Reverse Recovery Time <sup>2)</sup>	t <sub>rr</sub>	50			75			ns			
Typical Thermal Resistance <sup>3)</sup>	R <sub>θJA</sub> R <sub>θJC</sub>	60 20						°C/W			
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>stg</sub>	-55 ~ +150						°C			

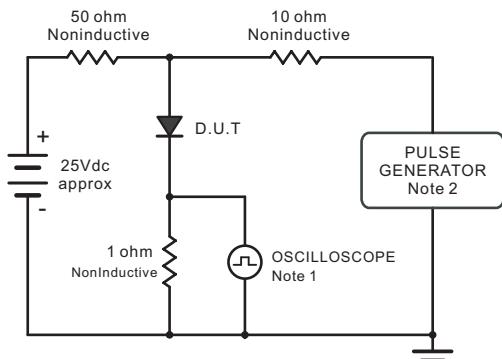
1 ) Measured at 1 MHz and applied reverse voltage of 4 V D.C

2 ) Measured with I<sub>F</sub> = 0.5 A, I<sub>R</sub> = 1 A, I<sub>rr</sub> = 0.25 A

3 ) P.C.B. mounted with 4×1.5"×1.5" ( 3.81×3.81 cm ) copper pad areas.



Fig.1 Reverse Recovery Time Characteristic And Test Circuit Diagram



Note: 1. Rise Time = 7ns, max.  
Input Impedance = 1megohm, 22pF.  
2. Ries Time = 10ns, max.  
Source Impedance = 50 ohms.

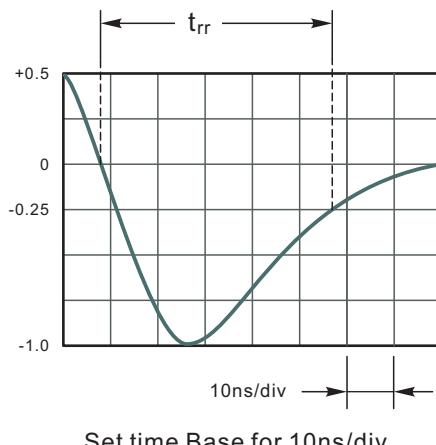


Fig.2 Maximum Average Forward Current Rating

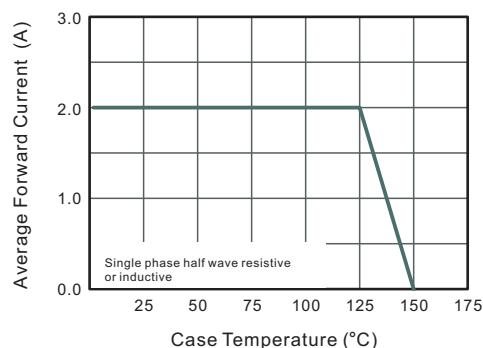


Fig.3 Typical Reverse Characteristics

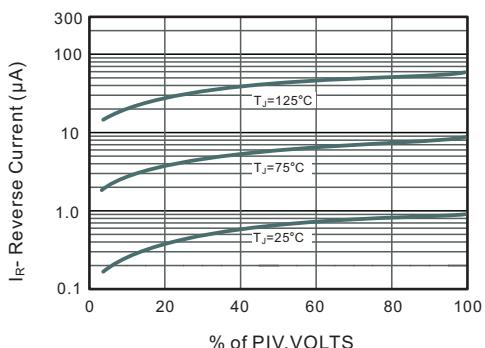


Fig.3 Typical Instantaneous Forward Characteristics

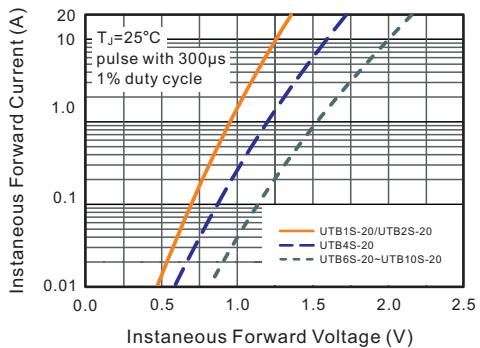
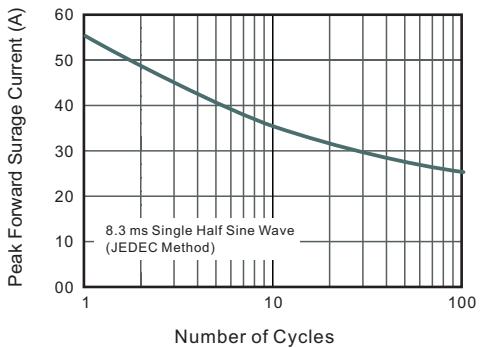


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

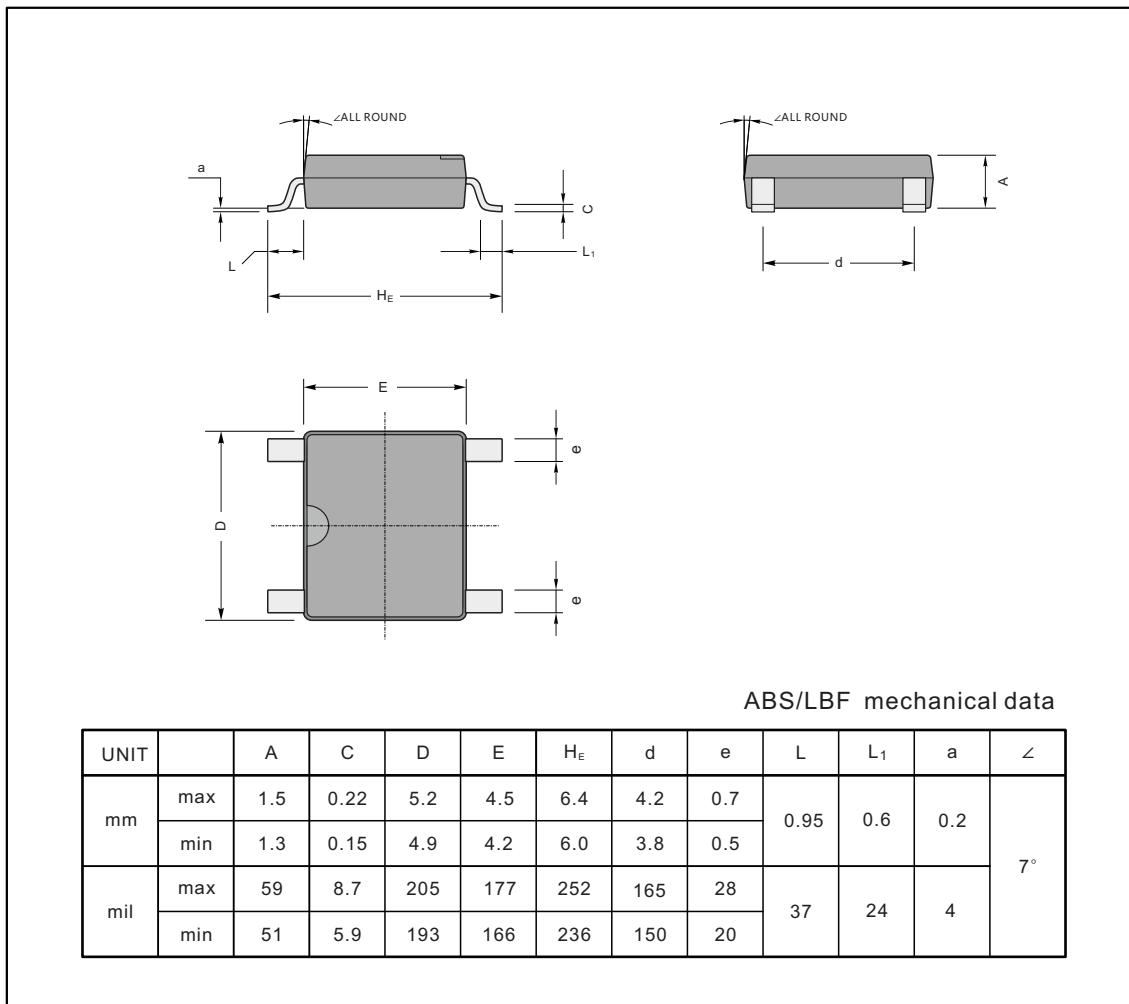




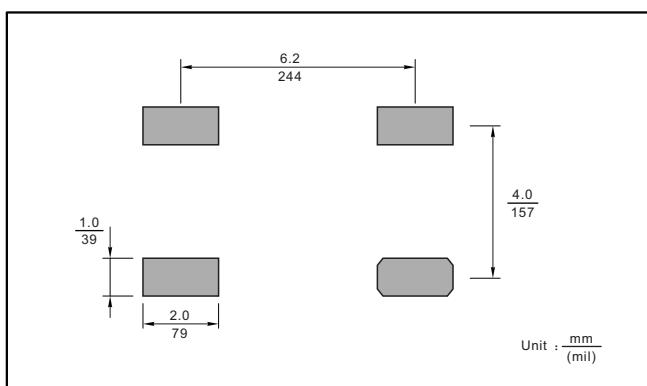
## PACKAGE OUTLINE

Plastic surface mounted package; 4 leads

ABS/LBF



## The recommended mounting pad size



## Marking

Type number	Marking code
UTB1S-20	U20T1
UTB2S-20	U20T2
UTB4S-20	U20T4
UTB6S-20	U20T6
UTB8S-20	U20T8
UTB10S-20	U20T10

A small diagram of the package showing the marking code U20Txx.

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